

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition
1	IS&R	1	("6180439").PN.	USPAT	2004/03/19 10:34		
2	IS&R	4	((("3890632") or ("4330363") or ("4466073") or ("5550070")).PN.	USPAT	2001/04/03 10:08		
3	BRS	1322	438/149,162,164,166,479,482,486,487.ccls.	USPAT	2001/04/03 10:09		
4	BRS	242	438/149,162,164,166,479,482,486,487.ccls. and (taper\$3 or slant\$3 or trapezoid\$2 or angl\$3)	USPAT	2001/04/03 10:11		
5	BRS	32	438/164.ccls. and (taper\$3 or slant\$3 or trapezoid\$2 or angl\$3)	USPAT	2001/04/03 10:12		
6	BRS	1	((silicon adj oxide) and (silicon adj oxynitride)).TI.	USPAT	2003/01/15 14:58		
7	BRS	63	((silicon adj oxide) and (silicon adj oxynitride))with (gate adj insulating)	USPAT	2004/09/07 14:47		
8	BRS	116	(silicon adj oxynitride) with TEOS	USPAT	2003/01/15 16:41		

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition
9	BRS	13	(silicon adj oxynitride) with (TEOS and nitrogen)	USPAT	2003/01/15 16:45		
10	BRS	14	(silicon adj oxynitride) and (TEOS with (nitrogen same oxide))	USPAT	2004/09/07 14:53		
11	IS&R	5	((("6465287") or ("6482686") or ("6495404") or ("6528358") or ("5970327"))).PN.	USPAT	2004/03/02 13:53		
12	BRS	799	Plasma with treatment with semiconductor	USPAT	2004/03/04 14:09		
13	BRS	86	(Plasma with treatment with semiconductor) and (semiconductor with organic)	USPAT	2004/03/04 15:01		
14	IS&R	1	("5728259").PN.	USPAT	2004/03/04 15:37		
15	BRS	726	134/1.2,1.3.ccls.	USPAT	2004/03/04 15:37		
16	BRS	16	134/1.2,1.3.ccls. and semiconductor and TFT	USPAT	2004/03/04 17:10		
17	BRS	2	organic adj diffusion adj barrier	USPAT	2004/03/04 17:10		

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition
18	BRS	146	organic with (diffusion adj barrier)	USPAT	2004/03/04 17:32		
19	BRS	98	(organic with (diffusion adj barrier)) and semiconductor	USPAT	2004/03/04 17:11		
20	BRS	108	resin with (diffusion adj barrier)	USPAT	2004/03/04 17:30		
21	BRS	5	(resin with (diffusion adj barrier)) and semiconductor	USPAT	2004/03/04 17:30		
22	BRS	394	organic same (diffusion adj barrier)	USPAT	2004/03/04 17:33		
23	BRS	278	(organic same (diffusion adj barrier)) and semiconductor	USPAT	2004/03/04 17:32		
24	BRS	2379	organic with diffusion	USPAT	2004/03/04 17:34		
25	BRS	14	organic adj diffusion	USPAT	2004/03/04 17:36		
26	BRS	181	resin with (environment\$2 adj protection)	USPAT	2004/03/04 17:36		

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition
27	BRS	30	(resin with (environment\$2 adj protection)) and semiconductor	USPAT	2004/03/04 17:36		
28	IS&R	4	((("6531862") or ("5575883") or ("5902993") or ("6006763"))).PN.	USPAT	2004/03/19 10:35		
29	IS&R	4	((("5531862") or ("5575883") or ("5902993") or ("6006763"))).PN.	USPAT	2004/03/19 10:36		
30	IS&R	1	("5728259").PN.	USPAT	2004/09/07 14:47		
31	IS&R	2	((("5147826") or ("4330363"))).PN.	USPAT	2004/09/07 15:06		
32	BRS	221	(amorphous adj silicon) and crystallization and (metal with catalyst)	USPAT	2004/09/07 15:08		
33	BRS	43	((amorphous adj silicon) and crystallization and (metal with catalyst)) and gettering	USPAT	2004/09/07 15:18		
34	BRS	190	gettering with halogen	USPAT	2004/09/07 15:19		

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition
35	BRS	167	(gettering with halogen) and silicon	USPAT	2004/09/07 16:21		
36	IS&R	1	("6180439").PN.	USPAT	2004/09/07 15:39		
37	BRS	78	(heavy adj metal) and getter\$3 and halogen	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 16:57		
38	BRS	86	gas with phase with getter\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 16:43		
39	BRS	12	(gas with phase with getter\$3) and halogen	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 16:34		
40	BRS	3	("5322590" "5658418" "5683538").PN.	USPAT	2004/09/07 16:37		

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition
41	BRS	13	("4417822" "4500563" "4647774" "4919542" "4956538" "4979134" "4984902" "5098197" "5154512" "5156461" "5226732" "5326171" "5387777").PN.	USPAT	2004/09/07 16:37		
42	BRS	13	("4417822" "4500563" "4647774" "4919542" "4956538" "4979134" "4984902" "5098197" "5154512" "5156461" "5226732" "5326171" "5387777").PN.	USPAT	2004/09/07 16:37		
43	BRS	1	"4816113".PN.	USPAT	2004/09/07 16:37		
44	BRS	46	(semiconductor with cleaning with halogen) and oxidation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 17:00		

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition
45	BRS	46	((semiconductor with cleaning with halogen) and oxidation) and (impurities or metal)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/08 10:36		
46	BRS	3260	film with irradiation with (UV or infrared)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 18:01		
47	BRS	15	(semiconductor adj film) with irradiation with (UV or infrared)	USPAT	2004/09/07 18:03		
48	BRS	27	(semiconductor adj film) with irradiation with (UV or infrared)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 18:06		
49	BRS	201	semiconductor with irradiation with (UV or infrared)	USPAT	2004/09/07 18:07		
50	IS&R	1	("5704986").PN.	USPAT	2004/09/08 12:57		
51	BRS	277	crystallization with infrared	USPAT	2004/09/08 12:58		
52	BRS	93	(crystallization with infrared) and (amorphous adj silicon)	USPAT	2004/09/09 09:41		

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition
53	IS& R	1	("6180439").PN.	USPAT	2004/09/09 09:41		